BAW56...

## Silicon Switching Diode

- For high-speed switching applications
- Common anode configuration
- BAW56S / U: For orientation in reel see package information below
- Pb-free (RoHS compliant) package ${ }^{1)}$
- Qualified according AEC Q101


| BAW56 | BAW56S |
| :--- | :--- |
| BAW56W | BAW56U |



| Type | Package | Configuration | Marking |
| :--- | :--- | :--- | :--- |
| BAW56 | SOT23 | common anode | A1s |
| BAW56S | SOT363 | double common anode | A1s |
| BAW56U | SC74 | double common anode | A1s |
| BAW56W | SOT323 | common anode | A1s |

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Maximum Ratings at $T_{\mathrm{A}}=25^{\circ} \mathrm{C}$, unless otherwise specified

| Parameter | Symbol | Value | Unit |
| :--- | :--- | :---: | :--- |
| Diode reverse voltage | $V_{\mathrm{R}}$ | 80 | V |
| Peak reverse voltage | $V_{\mathrm{RM}}$ | 85 |  |
| Forward current | $I_{\mathrm{F}}$ | 200 | mA |
| Non-repetitive peak surge forward current | $I_{\mathrm{FSM}}$ |  | A |
| $t=1 \mu \mathrm{~s}$ |  | 4.5 |  |
| $t=1 \mathrm{~ms}$ |  | 1 |  |
| $t=1 \mathrm{~s}$, single |  | 0.5 |  |
| $t=1 \mathrm{~s}$, double | $P_{\text {tot }}$ | 0.75 |  |
| Total power dissipation |  |  |  |
| BAW56, $T_{\mathrm{S}} \leq 28^{\circ} \mathrm{C}$ |  | 230 |  |
| BAW56S, $T_{\mathrm{S}} \leq 85^{\circ} \mathrm{C}$ |  | 250 |  |
| BAW56U, $T_{\mathrm{S}} \leq 90^{\circ} \mathrm{C}$ |  | 250 |  |
| BAW56W, $T_{\mathrm{S}} \leq 103^{\circ} \mathrm{C}$ |  | 150 | ${ }^{\circ} \mathrm{C}$ |
| Junction temperature | $T_{\mathrm{j}}$ | $-65 \ldots 150$ |  |
| Storage temperature | $T_{\text {stg }}$ |  |  |

Thermal Resistance

| Parameter | Symbol | Value | Unit |
| :--- | :--- | :--- | :--- |
| Junction - soldering point ${ }^{1)}$ | $R_{\text {thJS }}$ |  | K/W |
| BAW56 |  | 360 |  |
| BAW56S |  | 260 |  |
| BAW56U |  | 240 |  |
| BAW56W |  | 190 |  |

${ }^{1}$ For calculation of $R_{\mathrm{thJA}}$ please refer to Application Note Thermal Resistance

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Electrical Characteristics at $T_{\mathrm{A}}=25^{\circ} \mathrm{C}$, unless otherwise specified

| Parameter | Symbol | Values |  |  | Unit |
| :--- | :--- | :--- | :--- | :--- | :--- |
|  |  | min. | typ. | max. |  |

## DC Characteristics

| Breakdown voltage <br> $I_{(\mathrm{BR})}=100 \mu \mathrm{~A}$ | $V_{(\mathrm{BR})}$ | 85 | - | - | V |
| :--- | :--- | :--- | :--- | :--- | :--- |
| Reverse current | $I_{\mathrm{R}}$ |  |  |  | $\mu \mathrm{A}$ |
| $V_{\mathrm{R}}=70 \mathrm{~V}$ |  | - | - | 0.15 |  |
| $V_{\mathrm{R}}=25 \mathrm{~V}, T_{\mathrm{A}}=150^{\circ} \mathrm{C}$ |  | - | - | 30 |  |
| $V_{\mathrm{R}}=70 \mathrm{~V}, T_{\mathrm{A}}=150^{\circ} \mathrm{C}$ |  | - | - | 50 |  |
| Forward voltage | $V_{\mathrm{F}}$ |  |  |  | mV |
| $I_{\mathrm{F}}=1 \mathrm{~mA}$ |  | - | - | 715 |  |
| $I_{\mathrm{F}}=10 \mathrm{~mA}$ |  | - | - | 855 |  |
| $I_{\mathrm{F}}=50 \mathrm{~mA}$ |  | - | - | 1000 |  |
| $I_{\mathrm{F}}=100 \mathrm{~mA}$ |  | - | - | 1200 |  |
| $I_{\mathrm{F}}=150 \mathrm{~mA}$ | - | - | 1250 |  |  |

## AC Characteristics

| Diode capacitance <br> $V_{\mathrm{R}}=0 \mathrm{~V}, f=1 \mathrm{MHz}$ | $C_{\mathrm{T}}$ | - | - | 2 | pF |
| :--- | :--- | :--- | :--- | :--- | :--- |
| Reverse recovery time <br> $I_{F}=10 \mathrm{~mA}, I_{\mathrm{R}}=10 \mathrm{~mA}$, measured at $I_{\mathrm{R}}=1 \mathrm{~mA}$, | $t_{\mathrm{rr}}$ | - | - | 4 | ns |
| $R_{\mathrm{L}}=100 \Omega$ |  |  |  |  |  |

## Test circuit for reverse recovery time



Pulse generator: $t_{\mathrm{p}}=100 \mathrm{~ns}, D=0.05, t_{\mathrm{r}}=0.6 \mathrm{~ns}$,

$$
R_{\mathrm{i}}=50 \Omega
$$

Oscillograph: $R=50 \Omega, t_{\mathrm{r}}=0.35 \mathrm{~ns}, C \leq 1 \mathrm{pF}$

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Reverse current $I_{\mathrm{R}}=f\left(T_{\mathrm{A}}\right)$
$V_{R}=$ Parameter


Forward current $I_{F}=f\left(V_{F}\right)$
$T_{\mathrm{A}}=25^{\circ} \mathrm{C}$


Forward Voltage $V_{\mathrm{F}}=f\left(T_{\mathrm{A}}\right)$
$I_{F}=$ Parameter


Forward current $I_{\mathrm{F}}=f\left(T_{\mathrm{S}}\right)$
BAW56


Forward current $I_{\mathrm{F}}=f\left(T_{\mathrm{S}}\right)$
BAW56S


Forward current $I_{F}=f\left(T_{S}\right)$
BAW56W


Forward current $I_{F}=f\left(T_{S}\right)$
BAW56U


Permissible Puls Load $R_{\mathrm{th} J S}=f\left(t_{\mathrm{p}}\right)$ BAW56


Permissible Pulse Load
$I_{\text {Fmax }} / I_{\text {FDC }}=f\left(t_{\mathrm{p}}\right)$
BAW56


## Permissible Pulse Load

$I_{\text {Fmax }} / I_{\text {FDC }}=f\left(t_{\mathrm{p}}\right)$
BAW56S


Permissible Puls Load $R_{\text {thJS }}=f\left(t_{\mathrm{p}}\right)$ BAW56S


Permissible Puls Load $R_{\text {thJS }}=f\left(t_{\mathrm{p}}\right)$ BAW56U


Permissible Pulse Load
$I_{\text {Fmax }} / I_{\text {FDC }}=f\left(t_{\mathrm{p}}\right)$
BAW56U


## Permissible Pulse Load

$I_{\text {Fmax }} / I_{\text {FDC }}=f\left(t_{\mathrm{p}}\right)$
BAW56W


Permissible Puls Load $R_{\text {thJS }}=f\left(t_{\mathrm{p}}\right)$ BAW56W


Package Outline


Foot Print


## Marking Layout (Example)

Small variations in positioning of
Date code, Type code and Manufacture are possible.


## Standard Packing

Reel $\varnothing 180 \mathrm{~mm}=3.000$ Pieces/Reel
Reel $\varnothing 330 \mathrm{~mm}=10.000$ Pieces/Reel
For symmetric types no defined Pin 1 orientation in reel.


Package Outline


1) Lead width can be 0.6 max. in dambar area

Foot Print


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[^0]:    ${ }^{1} \mathrm{~Pb}$-containing package may be available upon special request

